



FEATURES

- **Standard 8-Pin Packages**
- **High Power Factor Over Wide Load Range with Line Current Averaging**
- International Operation Without Switches
- Instantaneous Overvoltage Protection
- Minimal Line Current Dead Zone
- Typical 250 μ A Start-Up Supply Current
- Rejects Line Switching Noise
- Synchronization Capability
- Low Quiescent Current: 9mA
- Fast 1.5A Peak Current Gate Driver

APPLICATIONS

- Universal Power Factor Corrected Power Supplies
- Preregulators up to 1500W

DESCRIPTION

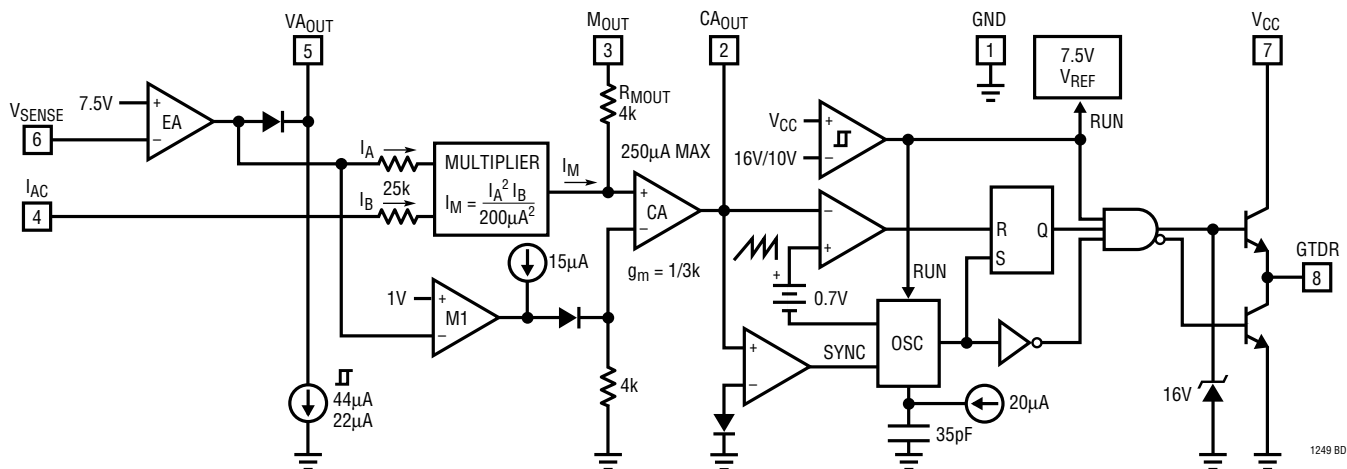
The 8-pin LT1249 provides active power factor correction for universal off-line power systems with very few external parts. By using fixed high frequency PWM current averaging without the need for slope compensation, the LT1249 achieves far lower line current distortion, with a smaller magnetic element than systems that use either peak current detection or zero current switching approach, in both continuous and discontinuous modes of operation.

The LT1249 uses a multiplier that has a square gain function from the voltage amplifier to reduce the AC gain at light output load and thus maintains low line current distortion and high system stability. The LT1249 also provides filtering capability to reject line switching noise which can cause instability when fed into the multiplier. Line current dead zone is minimized with low bias voltage at the current input to the multiplier.

The LT1249 provides many protection features including peak current limiting and overvoltage protection. The switching frequency is internally set at 100kHz.

While the LT1249 simplifies PFC design with minimal parts count, the LT1248 provides flexibilities in switching frequency, overvoltage, and current limit.

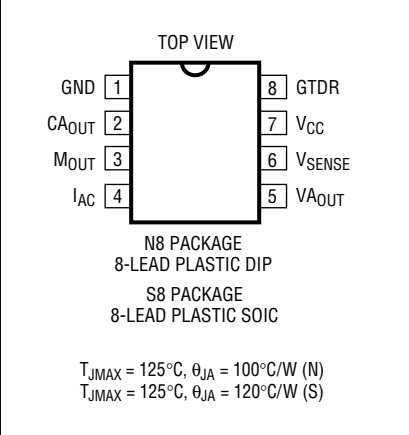
BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Supply Voltage	27V
GTDR Current Continuous	0.5A
GTDR Output Energy(Per Cycle)	5 μ J
I _{AC} Input Current	20mA
V _{SENSE} Input Voltage	V _{MAX}
M _{OUT} Input Current	±5mA
Operating Junction Temperature Range	
LT1249C	0°C to 100°C
LT1249I	–40°C to 125°C
Thermal Resistance (Junction-to-Ambient)	
N Package	100°C/W
S Package	120°C/W
Storage Temperature Range	–65°C to 150°C
Lead Temperature (Soldering, 10 sec)	300°C

PACKAGE/ORDER INFORMATION

TOP VIEW  N8 PACKAGE 8-LEAD PLASTIC DIP S8 PACKAGE 8-LEAD PLASTIC SOIC T_{JMAX} = 125°C, θ_{JA} = 100°C/W (N) T_{JMAX} = 125°C, θ_{JA} = 120°C/W (S)	ORDER PART NUMBER
	LT1249CN8 LT1249IN8 LT1249CS8 LT1249IS8
	S8 PART MARKING
	1249 1249I

Consult factory for Military grade parts.

ELECTRICAL CHARACTERISTICS

Maximum operating voltage (V_{MAX}) = 25V, V_{CC} = 18V, I_{AC} = 100 μ A, CA_{OUT} = 3.5V, VA_{OUT} = 5V, no load on any outputs, unless otherwise noted.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Overall						
Supply Current (V _{CC} in Undervoltage Lockout)	V _{CC} = Lockout Voltage – 0.2V	●	0.25	0.45		mA
Supply Current, On	11.5V ≤ V _{CC} ≤ V _{MAX}	●	8	12		mA
V _{CC} Turn-On Threshold		●	15.5	16.5	17.5	V
V _{CC} Turn-Off Threshold		●	9.5	10.5	11.5	V
Voltage Amplifier						
V _{SENSE} Bias Current	V _{SENSE} = 0V to 7V	●	–25	–250		nA
Voltage Amp Gain			70	100		dB
Voltage Amp Unity-Gain Bandwidth			1.5			MHz
Voltage Amp Output High	0 ≤ Source Current ≤ 50μA	●	10	12		V
Voltage Amp Output Low	0 ≤ Sink Current ≤ 5μA	●	0.1	0.4		V
Voltage Amp Source Current		●	130	260	450	μA
Voltage Amp Sink Current Threshold	Linear Operation, 2V < V _{AOUT} < 10V	●	33	44	57	μA
Voltage Amp Sink Current Hysteresis	2V < V _{AOUT} < 10V	●	14	22.5	30	μA
Current Amplifier						
Current Amp Offset Voltage		●	±2	±15		mV
Current Amp Transconductance	ΔI _{CAOUT} = ±40μA	●	150	320	550	μmho
Current Amp Voltage Gain	2.5V ≤ V _{CAOUT} ≤ 7.5V		500	1000		V/V
Current Amp Source Current	V _{MOUT} = 1V, I _M = 0μV		100	145	220	μA
Current Amp Sink Current	V _{MOUT} = –0.3V, I _M = 0μA		67	95	125	μA
Current Amp Output High			7.4	8.1		V
Current Amp Output Low			1.2	2		V

ELECTRICAL CHARACTERISTICS

Maximum operating voltage (V_{MAX}) = 25V, V_{CC} = 18V, I_{AC} = 100 μ A, CA_{OUT} = 3.5V, VA_{OUT} = 5V, no load on any outputs, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Reference					
Reference Output Voltage	$T_A = 25^\circ\text{C}$, Measured at V_{SENSE} Pin	7.39	7.5	7.6	V
Reference Output Voltage Worst Case	All Line, Temperature	● 7.32	7.5	7.68	V
Reference Output Voltage Line Regulation	$V_{LOCKOUT} < V_{CC} < V_{MAX}$	● -20	5	20	mV
Multiplier					
Multiplier Output Current	$I_{AC} = 100\mu\text{A}$, $VA_{OUT} = 5\text{V}$		35		μA
Multiplier Output Current Offset	$R_{AC} = 1\text{M}$ from I_{AC} to GND	● -0.05	-0.5		μA
Multiplier Max Output Current ($I_{M(MAX)}$)	$I_{AC} = 450\mu\text{A}$, $VA_{OUT} = 7\text{V}$ (Note 1)	● -375	-250	-150	μA
Multiplier Max Output Voltage ($I_{M(MAX)} \times R_{MOUT}$)	$I_{AC} = 450\mu\text{A}$, $VA_{OUT} = 7\text{V}$ (Note 1)	● -1.25	-1.1	-0.96	V
Multiplier Gain Constant (Note 2)			0.035		V^{-2}
I_{AC} Input Resistance	I_{AC} from 50 μA to 1mA	15	25	35	$\text{k}\Omega$
Oscillator					
Oscillator Frequency		● 75	100	125	kHz
Control Pin (CA_{OUT}) Threshold	Duty Cycle = 0	● 1.3	1.8	2.3	V
Synchronization Frequency Range	Synchronizing Pulse Low $\leq 0.35\text{V}$ on CA_{OUT}	● 127		160	kHz
Gate Driver					
Max GTDR Output Voltage	0mA Load, $18\text{V} < V_{CC} < V_{MAX}$ (Note 3)	● 12	15	17.5	V
GTDR Output High	-200mA Load, $11.5\text{V} \leq V_{CC} \leq 15\text{V}$	● $V_{CC} - 3.0$			V
GTDR Output Low (Device Unpowered)	$V_{CC} = 0\text{V}$, 50mA Load (Sinking)	● 0.9	1.5		V
GTDR Output Low (Device Active)	200mA Load (Sinking)	● 0.5	1		V
Peak GTDR Current	10nF from GTDR to GND		2		A
GTDR Rise and Fall Time	1nF from GTDR to GND		25		ns
GTDR Max Duty Cycle		90	96		%

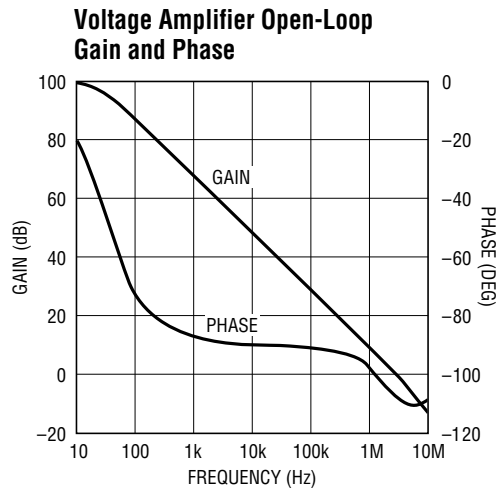
The ● denotes specifications which apply over the operating temperature range.

Note 1: Current amplifier is in linear mode with 0V input common mode.

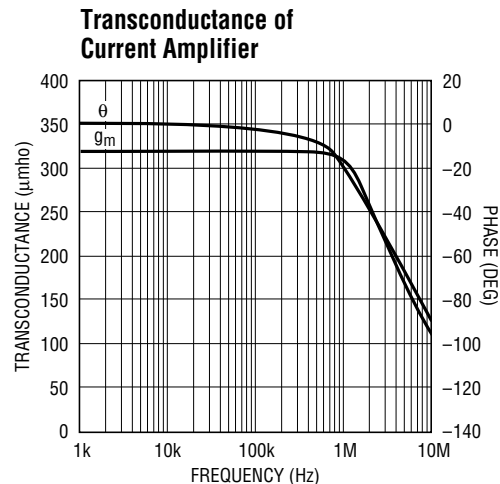
Note 2: Multiplier Gain Constant: $K = \frac{I_M}{I_{AC} (VA_{OUT} - 1.5)^2}$

Note 3: Maximum GTDR output voltage is internally clamped for higher V_{CC} voltages.

TYPICAL PERFORMANCE CHARACTERISTICS



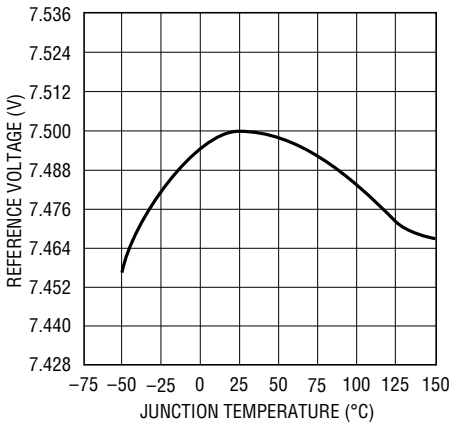
1249 G01



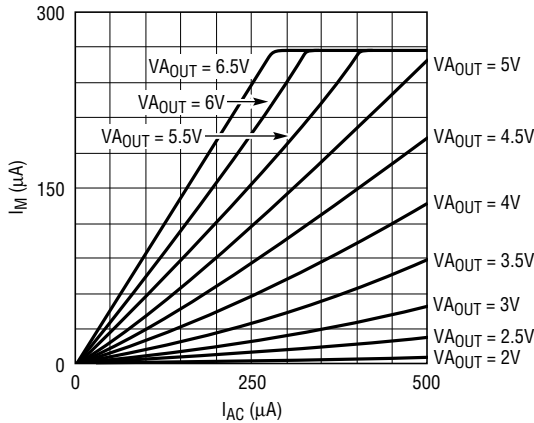
1249 G02

TYPICAL PERFORMANCE CHARACTERISTICS

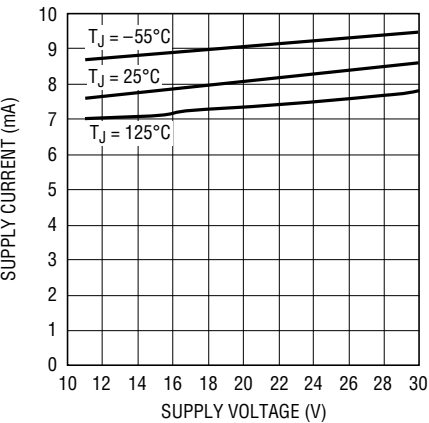
Reference Voltage vs Temperature



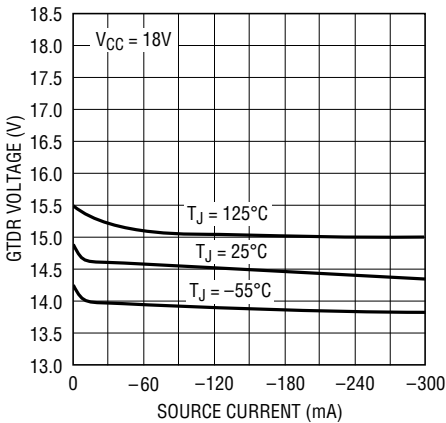
Multiplier Current



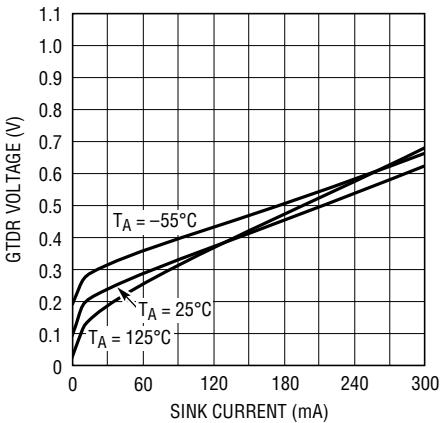
Supply Current vs Supply Voltage



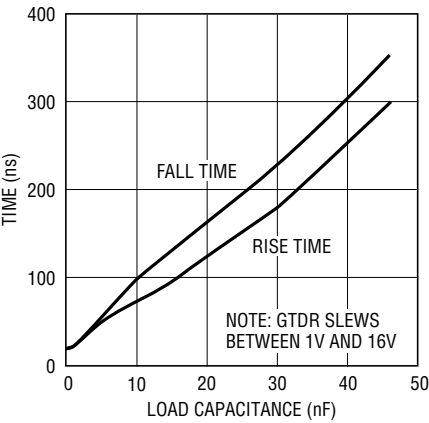
GTDR Source Current



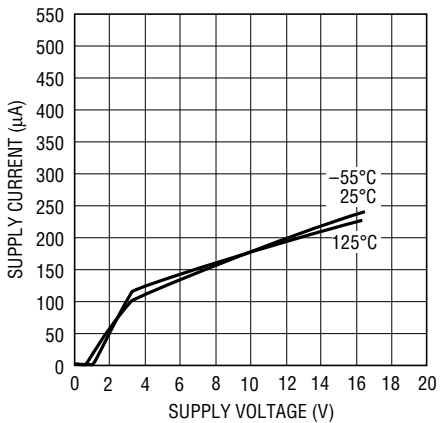
GTDR Sink Current



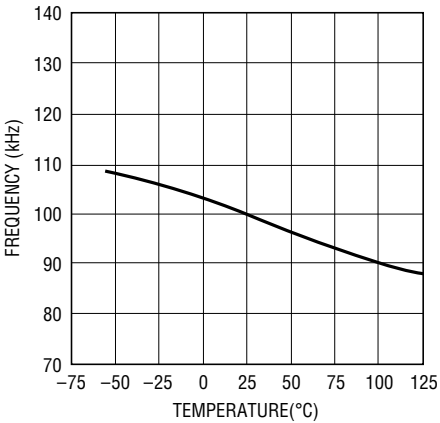
GTDR Rise and Fall Time



Start-Up Supply Current vs Supply Voltage

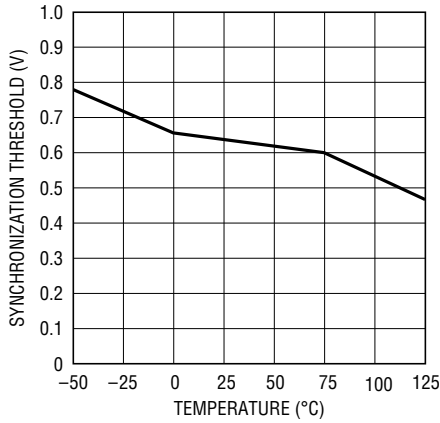


Switching Frequency



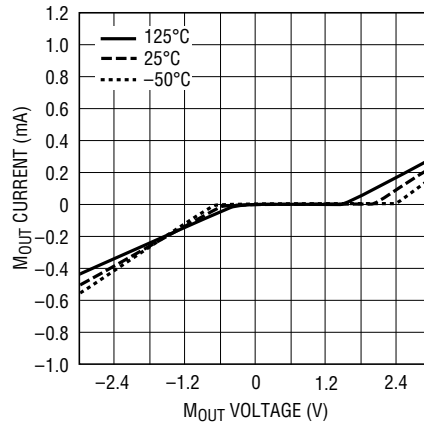
TYPICAL PERFORMANCE CHARACTERISTICS

Synchronization Threshold at CA_{OUT}



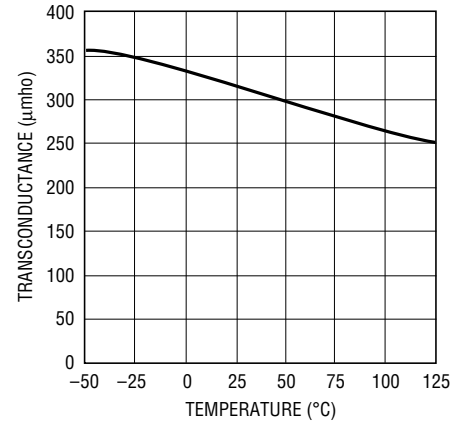
1249 G11

M_{OUT} Pin Characteristics



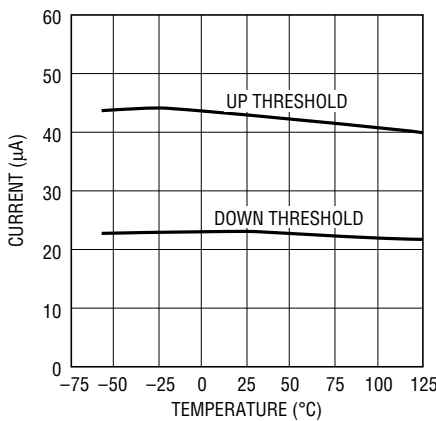
1249 G12

Transconductance of Current Amplifier Over Temperature



1249 G13

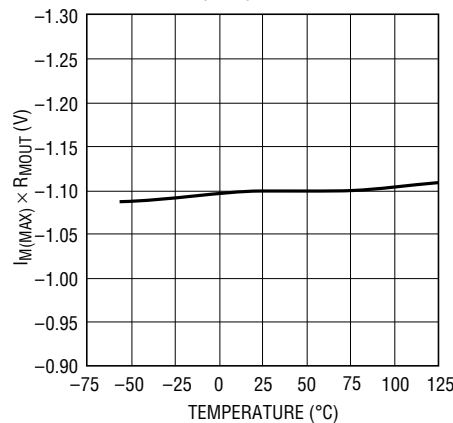
Voltage Amp Sink Current Limits (Threshold)



1249 G14

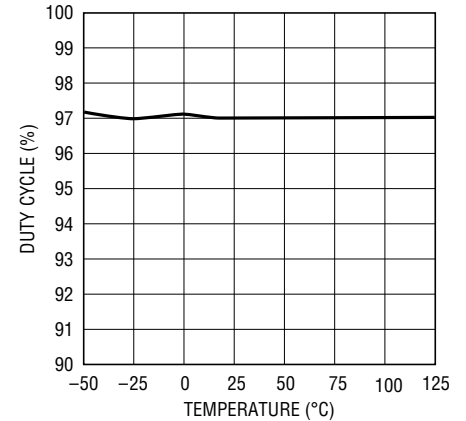
NOTE: THESE SINK CURRENT THRESHOLDS ARE FOR OVERVOLTAGE PROTECTION FUNCTION.

Maximum Multiplier Output Voltage ($I_{M(MAX)} \times R_{MOUT}$)



1249 G15

Maximum Duty Cycle



1249 G16

PIN FUNCTIONS

GND (Pin 1): Ground.

CA_{OUT} (Pin 2): This is the output of the current amplifier that senses and forces the line current to follow the reference signal that comes from the multiplier by commanding the pulse width modulator. When CA_{OUT} is low, the modulator has zero duty cycle.

M_{OUT} (Pin 3): The multiplier current goes out of this pin through the 4k resistor R_{MOUT}. The voltage developed across R_{MOUT} is the reference voltage of the current loop and it is limited to 1.1V. The noninverting input of the current amplifier is also tied to R_{MOUT}. In operation, M_{OUT}

is normally at negative potential and only AC signals appear at the noninverting input of the current amplifier.

I_{AC} (Pin 4): This is the AC line voltage sensing input to the multiplier. It is a current input that is biased at 2V to minimize the crossover dead zone caused by low line voltage. A 25k resistor is in series with the current input, so that a small external capacitor can be used to filter out the switching noise from the high impedance lines.

VA_{OUT} (Pin 5): This is the output of the voltage error amplifier. The output is clamped at 12V. When the output goes below 1.5V, the multiplier output current is zero.

PIN FUNCTIONS

V_{SENSE} (Pin 6): This is the inverting input to the voltage amplifier.

GTDR (Pin 7): The MOSFET gate driver is a 1.5A fast totem pole output. It is clamped at 15V. Capacitive loads like MOSFET gates may cause overshoot. A gate series resistor of at least 5Ω will prevent the overshoot.

V_{CC} (Pin 8): This is the supply of the chip. The LT1249 has a very fast gate driver required to fast charge high power MOSFET gate capacitance. High current spikes occur during charging. For good supply bypass, a 0.1μF ceramic capacitor in parallel with a low ESR electrolytic capacitor, 56μF or higher is required in close proximity to IC GND.

APPLICATIONS INFORMATION

Error Amplifier

The error amplifier has a 100dB DC gain and 1.5MHz unity-gain frequency. It is internally clamped at 12V. The non-inverting input is tied to the 7.5V reference.

Current Amplifier

The multiplier output current I_M flows out of the M_{OUT} pin through the 4k resistor R_{MOUT} and develops the reference signal to the current loop that is controlled by the current amplifier. Current gain is the ratio of R_{MOUT} to line current sense resistor. The current amplifier is a transconductance amplifier. Typical g_m is 320μmho and gain is 60dB with no load. The inverting input is internally tied to GND. The noninverting input is tied to the multiplier output. The output is internally clamped at 8V. Output resistance is about 4M; DC loading should be avoided because it will lower the gain and introduce offset voltage at the inputs which becomes a false reference signal to the current loop and can distort line current. Note that in the current averaging operation, high gain at twice the line frequency is necessary to minimize line current distortion. Because CA_{OUT} may need to swing 5V over one line cycle at high line condition, 11mV will be present at the inputs of the current amplifier if gain is rolled off to 450 at 120Hz (1nF in series with 10k at CA_{OUT}). At light load, when $(I_M)(R_{MOUT})$ can be less than 100mV, lower gain will distort the current loop reference signal and line current. If signal gain at the 100kHz switching frequency is too high, the system behaves more like a current mode system and can cause subharmonic oscillation. Therefore, the current amplifier should be compensated to have a gain of less than 15 at 100kHz and more than 300 at 120Hz.

Multiplier

The multiplier is a current multiplier with high noise immunity in a high power switching environment. The current gain is:

$$I_M = (I_{AC} \times I_{EA}^2) / (200\mu A)^2, \text{ and}$$

$$I_{EA} = (V_{AOUT} - 1.5V) / 25k$$

With a square function, because of the lower gain at light power load, system stability is maintained and line current distortion caused by the AC ripple fed back to the error amplifier is minimized. Note that switching ripple on the high impedance lines could get into the multiplier from the I_{AC} pin and cause instability. The LT1249 provides an internal 25k resistor in series with the low impedance multiplier current input so that only a capacitor from the I_{AC} pin to GND is needed to filter out the noise. Maximum multiplier output current is limited to 250μA. Figure 1 shows the multiplier transfer curves.

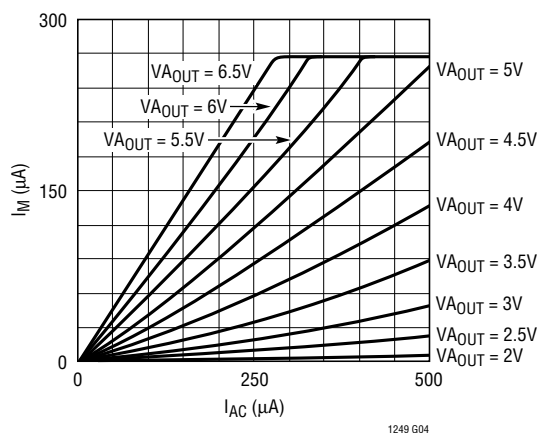


Figure 1. Multiplier Current I_M vs I_{AC} and V_{AOUT}

APPLICATIONS INFORMATION

The Figure 3 circuit therefore has 382V on V_{OUT} , and an overvoltage level = $(V_{OUT} + 44V)$, or 426V. With a 22 μA hysteresis, V_{OUT} then has to drop 22V to 404V before feedback recovers and the switch turns back on.

M_{OUT} is a high impedance current output. In the current loop, offset line current is determined by multiplier offset current and input offset voltage of the current amplifier. A negative 4mV current amplifier V_{OS} translates into 20mA line current and 5W input power for 250V line if 0.2 Ω sense resistor is used. Under no load or when the load power is less than this offset input power, V_{OUT} would slowly charge up to an overvoltage state because the overvoltage comparator can only reduce multiplier output current to zero. This does not guarantee zero output current if the current amplifier has offset. To regulate V_{OUT} under this condition, the amplifier M1 (see Block Diagram), becomes active in the current loop when V_{AOUT} goes down to 1V. The M1 can put out up to 15 μA to the 4k resistor at the inverting input to cancel the current amplifier negative V_{OS} and keep V_{OUT} error to within 2V.

Undervoltage Lockout

The LT1249 turns on when V_{CC} is higher than 16V and remains on until V_{CC} falls below 10V, whereupon the chip enters the lockout state. In the lockout state, the LT1249 only draws 250 μA , the oscillator is off, the V_{REF} and the GTDR pins remain low to keep the power MOSFET off.

Start-Up and Supply Voltage

The LT1249 draws only 250 μA before the chip starts at 16V on V_{CC} . To trickle start, a 90k resistor from the power line to V_{CC} supplies the trickle current and C4 holds the V_{CC} up while switching starts (see Figure 4). Then the auxiliary winding takes over and supplies the operating current. Note that D3 and the large value C3, in both Figures 4 and 5, are only necessary for systems that have sudden large load variation down to minimum load and/or very light load conditions. Under these conditions, the loop may exhibit a start/restart mode because switching remains off long enough for C4 to discharge below 10V. The C3 will hold V_{CC} up until switching resumes. For less severe load variations, D3 is replaced with a short and C3 is omitted. The turns ratio between the primary winding and the

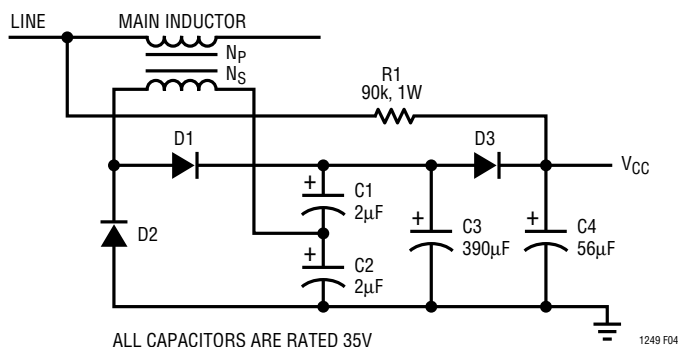


Figure 4. Power Supply for LT1249

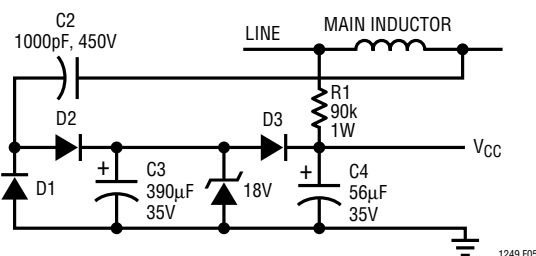


Figure 5. Power Supply for LT1249

auxiliary winding determines V_{CC} according to: $V_{OUT}/(V_{CC} - 2V) = N_p/N_s$. For 382V V_{OUT} and 18V V_{CC} , $N_p/N_s \approx 19$.

In Figure 5 a new technique for supply voltage eliminates the need for an extra inductor winding. It uses capacitor charge transfer to generate a constant current source which feeds a Zener diode. Current to the Zener is equal to $(V_{OUT} - V_Z)(C)(f)$, where V_Z is Zener voltage and f is switching frequency. For $V_{OUT} = 382V$, $V_Z = 18V$, $C = 1000pF$, and $f = 100kHz$, Zener current will be 36mA. This is enough to operate the LT1249, including the FET gate drive.

Output Capacitor

The peak-to-peak 120Hz output ripple is determined by:

$$V_{P-P} = (2)(I_{LOADDC})(Z)$$

where I_{LOADDC} : DC load current

Z : capacitor impedance at 120Hz

For 180 μF at 300W load, $I_{LOADDC} = 300W/385V = 0.78A$,

APPLICATIONS INFORMATION

$V_{P-P} = 2 \times 0.78A \times 7.4\Omega = 11.5V$. If less ripple is desired, higher capacitance should be used.

The selection of the output capacitor should also be based on the operating ripple current through the capacitor.

The ripple current can be divided into three major components. The first is at 120Hz whose RMS value is related to the DC load current as follows:

$$I_{1RMS} \approx 0.71 \times I_{LOADDC}$$

The second component contains the PF switching frequency ripple current and its harmonics. Analysis of this ripple is complicated because it is modulated with a 120Hz signal. However, computer numerical integration and Fourier analysis approximate the RMS value reasonably close to the bench measurements. The RMS value is about 0.82A at a typical condition of 120VAC, 200W load. This ripple is line voltage dependent, and the worst case is at low line.

$$I_{2RMS} = 0.82A \text{ at } 120VAC, 200W$$

The third component is the switching ripple from the load, if the load is a switching regulator.

$$I_{3RMS} \approx I_{LOADDC}$$

For United Chemicon KMH 400V capacitor series, ripple current multiplier for currents at 100kHz is 1.43. The equivalent 120Hz ripple current can then be found:

$$I_{RMS} = \sqrt{(I_{1RMS})^2 + \left(\frac{I_{2RMS}}{1.43}\right)^2 + \left(\frac{I_{3RMS}}{1.43}\right)^2}$$

For a typical system that runs at an average load of 200W and 385V output:

$$I_{LOADDC} = 0.52A$$

$$I_{1RMS} \approx 0.71 \times 0.52A = 0.37A$$

$$I_{2RMS} \approx 0.82A \text{ at } 120VAC$$

$$I_{3RMS} \approx I_{LOADDC} = 0.52A$$

$$I_{RMS} = \sqrt{(0.37A)^2 + \left(\frac{0.82A}{1.43}\right)^2 + \left(\frac{0.52A}{1.43}\right)^2} = 0.77A$$

The 120Hz ripple current rating at 105°C ambient is 0.95A for the 180μF KMH 400V capacitor. The expected life of the output capacitor may be calculated from the thermal stress analysis:

$$L = L_0 \times 2^{\frac{(105^\circ C + \Delta T_K) - (T_{AMB} + \Delta T_O)}{10}}$$

where

L = expected life time

L_0 = hours of load life at rated ripple current and rated ambient temperature

ΔT_K = capacitor internal temperature rise at rated condition. $\Delta T_K = (I^2 R)/(KA)$, where I is the rated current, R is capacitor ESR, and KA is a volume constant.

T_{AMB} = operating ambient temperature

ΔT_O = capacitor internal temperature rise at operating condition

In our example, $L_0 = 2000$ hours and $\Delta T_K = 10^\circ C$ at rated 0.95A. ΔT_O can then be calculated from:

$$\Delta T_O = \left(\frac{I_{RMS}}{0.95A}\right)^2 \times \Delta T_K = \left(\frac{0.77A}{0.95A}\right)^2 \times 10^\circ C = 6.6^\circ C$$

Assuming the operating ambient temperature is 60°C, the approximate life time is:

$$L_0 \approx 2000 \times 2^{\frac{(105^\circ C + 10^\circ C) - (60^\circ C + 6.6^\circ C)}{10}} \approx 57,000 \text{ Hrs.}$$

For longer life, capacitor with higher ripple current rating or parallel capacitors should be used.

[illegible]

1249 TA01

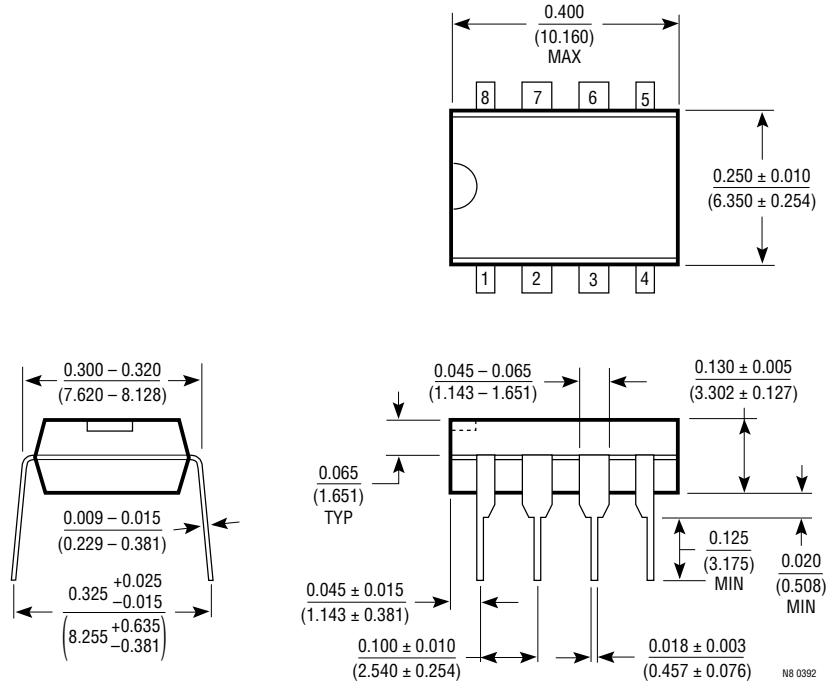
† SEE APPLICATIONS INFORMATION SECTION FOR CIRCUITRY TO SUPPLY POWER TO V_{CC} .

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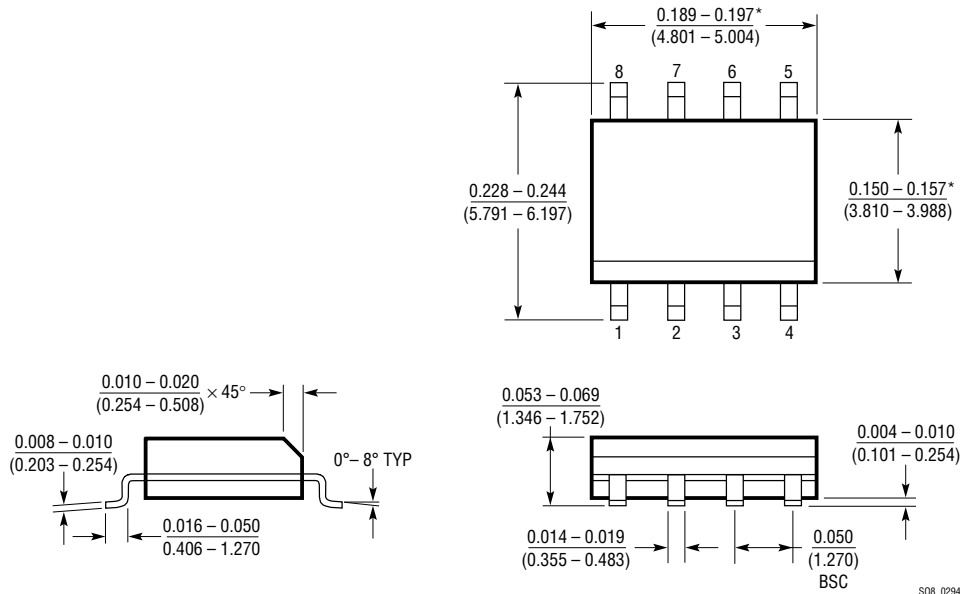
PACKAGE DESCRIPTION

Dimensions in inches (millimeters) unless otherwise noted.

N8 Package 8-Lead Plastic DIP



S8 Package 8-Lead Plastic SOIC



*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.006 INCH (0.15mm).

U.S. Area Sales Offices

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